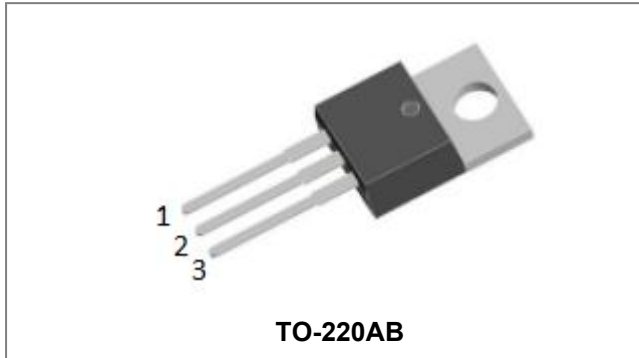


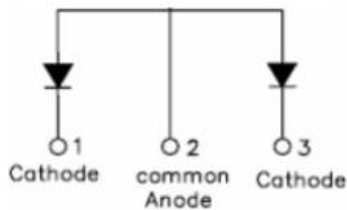
SDUR1660CTR ULTRAFAST RECTIFIER



Applications

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

Circuit Diagram



Features

- Ultra-Fast switching
- High current capability
- Low reverse leakage current
- High surge current capability
- Terminals finish: 100% Pure Tin
- This is a Pb – free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	-	600	V
Average Rectified Forward Current	$I_{F(AV)}$	$T_c=120^\circ\text{C}$, In DC	8(Per Leg) 16(Per Device)	A
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I_{FSM}	8.3ms, Half Sine pulse, $T_c= 25^\circ\text{C}$	80	A

Electrical Characteristics:

Characteristics	Symbol	Condition	Min.	Typ.	Max.	Units	
Forward Voltage Drop(Per Leg)*	V_{F1}	@8A, Pulse, $T_J = 25^\circ\text{C}$	-	1.3	1.5	V	
	V_{F2}	@8A, Pulse, $T_J = 125^\circ\text{C}$	-	1.2	1.4	V	
Reverse Current(Per Leg)*	I_{R1}	@ $V_R = \text{rated } V_R$, $T_J = 25^\circ\text{C}$	-	0.3	5	μA	
	I_{R2}	@ $V_R = \text{rated } V_R$, $T_J = 125^\circ\text{C}$	-	84	500	μA	
Reverse Recovery Time(Per Leg)	t_{rr}	$I_F=500\text{mA}$, $I_R=1\text{A}$, and $I_{rm}=250\text{mA}$ $T_J = 25^\circ\text{C}$	-	42	50	ns	
Isolation Voltage	V_{ISO}	$t = 1.0 \text{ second}$	50/60HZ, RMS; $I_{ISO} \leq 1\text{mA}$	3000	-	-	V
		$t = 1.0 \text{ minute}$		2500	-	-	

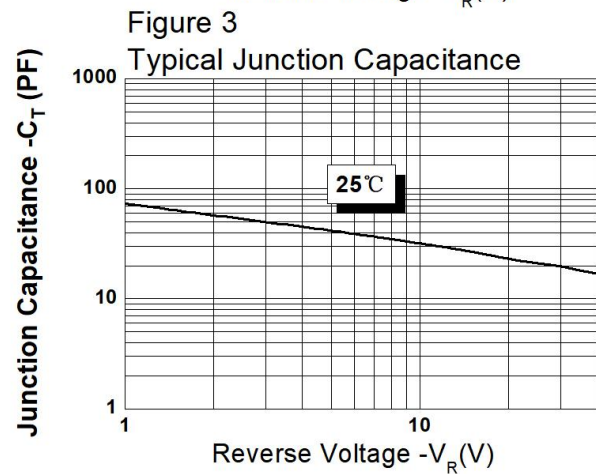
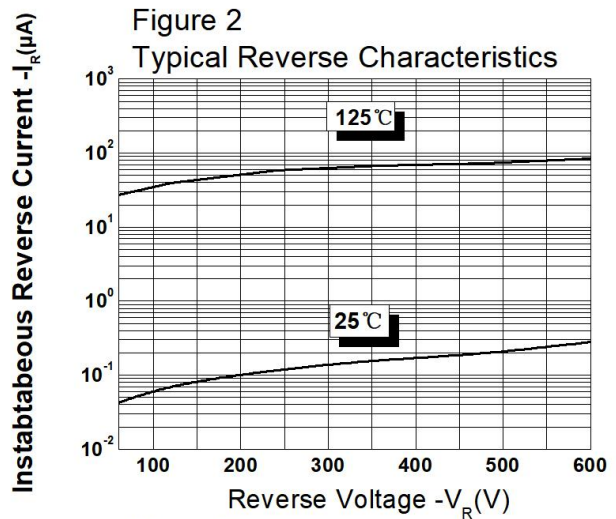
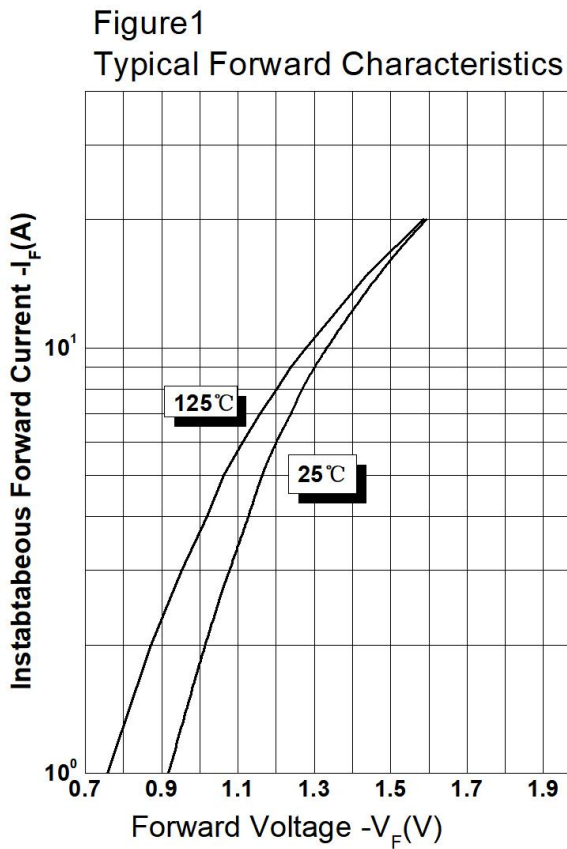
* Pulse width < 300 μs , duty cycle < 2%

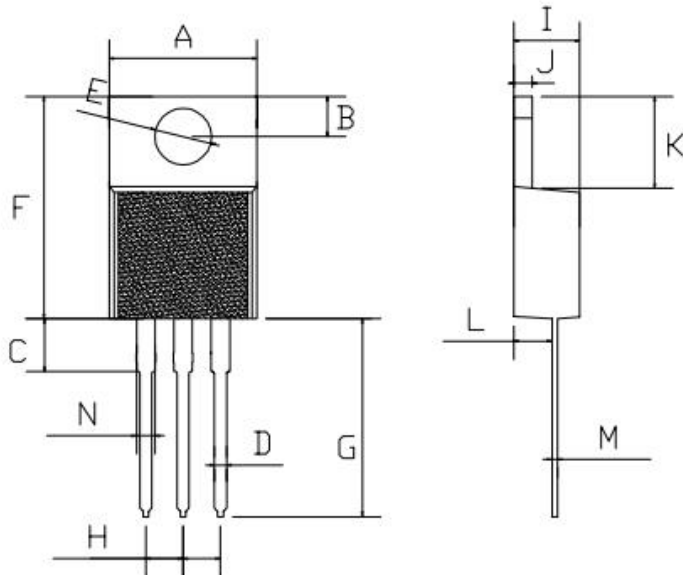
- China - Germany - Korea - Singapore - United States •
- <http://www.smc-diodes.com> - sales@smc-diodes.com •

Thermal-Mechanical Specifications:

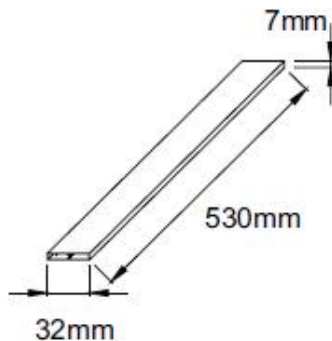
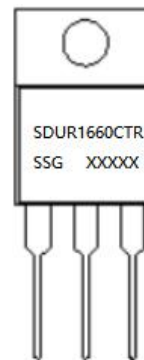
Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	T_J	-	-55 to +150	°C
Storage Temperature	T_{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	$R_{\theta JC}$	DC operation	2.5	°C/W
Approximate Weight	wt	-	2	g
Case Style	TO-220AB			

Ratings and Characteristics Curves



Mechanical Dimensions TO-220AB


SYMBOL	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	9.7	10.4	0.381	0.409
B	2.5	3.0	0.098	0.118
C	3.5	3.9	0.137	0.153
D	0.7	0.92	0.027	0.036
E	3.72	3.95	0.146	0.155
F	14.51	15.55	0.571	0.612
G	12.95	13.9	0.509	0.547
H	2.40	2.70	0.094	0.204
I	4.38	4.65	0.172	0.106
J	1.15	1.36	0.045	0.053
K	5.86	6.38	0.230	0.251
L	2.35	2.85	0.092	0.112
M	0.32	0.58	0.012	0.022
N	1.18	1.42	0.046	0.055

Tube Specification

Marking Diagram


Where XXXXX is YYWWL

SDUR = Device Type
 16 = Forward Current (16A)
 60 = Reverse Voltage(600V)
 CTR = Configuration
 SSG = SSG
 YY = Year
 WW = Week
 L = Lot Number

Cautions: Molding resin
 Epoxy resin UL:94V-0

Ordering Information

Device	Package	Shipping
SDUR1660CTR	TO-220AB (Pb-Free)	50 pcs/ tube

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2- In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment, and safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement.

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